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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Applicants: AKIMOTO et al.  
Serial No.: 09/955,275  
Filed: September 19, 2001  
For: FIELD EFFECT TRANSISTOR AND IMAGE DISPLAY APPARATUS USING THE SAME  
Group: 2811  
Examiner: G. Munson

AMENDMENT

Assistant Commissioner  
for Patents  
Washington, D.C. 20231

March 10, 2003

Sir:

In response to the Office Action dated October 8, 2002, the period of response for which extension is requested by the attached Petition for Extension of Time, please amend the above-identified application as follows:

In the Claims:

Please amend claims 1-16 as follows:

1. (Amended) An insulated gate field effect transistor having a gate electrode overlapping a channel area between a first conductivity type source area and a second conductivity type source area thereof, wherein:

said channel area provides a single channel between said first and second conductivity type source areas and includes a non-overlapped area portion free from being overlapped by the gate electrode in plan.

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